Electronic fine structure in the nickel carbide superconductor Th₂NiC₂

Y. Quan and W. E. Pickett

Department of Physics, University of California, Davis, California 95616, USA (Received 2 April 2013; revised manuscript received 6 June 2013; published 1 July 2013)

The recently reported nickel carbide superconductor body centered tetragonal I4/mmm Th₂NiC₂ with $T_c = 8.5$ K increasing to 11.2 K upon alloying Th with Sc is found to have very fine structure in its electronic spectrum, according to density functional based first-principles calculations. The filled Ni 3d band complex is hybridized with C 2p and Th character to and through the Fermi level (E_F), and a sharply structured density of states arises only when spin-orbit coupling is included, which splits a zone-center degeneracy, leaving a very flat band edge lying at the Fermi level. The flat part of the band corresponds to an effective mass $m_z^* \to \infty$ with large and negative $m_x^* = m_y^*$. Although the region over which the effective mass characterization applies is less than 1% of the zone volume, it supplies on the order of half the states at (or just above) the Fermi level. The observed increase of T_c by hole doping is accounted for if the reference as-synthesized sample is minutely hole doped, which decreases the Fermi level density of states and will provide some stabilization. In this scenario, electron doping will increase the Fermi level density of states and the superconducting critical temperature. Vibrational properties are presented, and enough coupling to the C-Ni-C stretch mode at 70 meV is obtained to imply that superconductivity is electron-phonon mediated.

DOI: 10.1103/PhysRevB.88.014501 PACS number(s): 74.20.Pq, 74.25.Kc, 74.62.Bf

I. INTRODUCTION

The discovery of new superconductors in the last dozen years, with MgB_2 found to be superconducting at $T_c=40~\rm K$ (see Refs. 1,2) and Fe-based pnictide and chalcogenide superconductors (FeSCs) up to 56 K, has reinvigorated the search for new superconductors. While MgB_2 remains a class of one material, the FeSCs like the cuprates have blossomed into several subclasses with dozens of members. The discovery of a new Ni-C superconductor in a distinct structural class provides reason for rapid follow up to understand its properties, establish its relationships to other superconductors, and perhaps to extend the class.

The recent discovery by Machado, Grant, and Fisk³ (MGF) that Th₂NiC₂ superconducts at $T_c = 8.5$ K, increasing to 11.2 K when alloyed with Sc, raises questions besides whether it might lead to other members of this structural class,⁴ possibly with higher T_c . Notably, MGF have categorized it as a very low-density-of-states (DOS) superconductor, because the specificheat coefficient extrapolated from a C(T)/T versus T^2 plot is vanishingly small—certainly an exceptional feature and one that is difficult to reconcile with metallic and superconducting behavior. Second, it is another transition metal (Ni) based superconductor, calling to mind the cuprates and FeSCs.

A central structural motif, Ni bonded to a metalloid (C or B) which in this case is in the form of the linear C-Ni-C trimer, reminds one of the rare-earth (\mathcal{R}) Ni borocarbides $\mathcal{R}\mathrm{Ni_2B_2C}$ that have attracted a great deal of attention,^{5,6} largely for the competition between \mathcal{R} magnetic ordering and superconductivity, and related members. The compound with the largest $T_c = 23$ K, $\mathrm{YPd_2B_2C}$, is based on isovalent Pd, suggesting substitutions in $\mathrm{Th_2NiC_2}$. $\mathrm{YNi_2B_2C}$ and similarly $\mathrm{LuNi_2B_2C}$ have a Ni-dominated density of states peak^{7,8} at E_F that promotes superconductivity (as well as other instabilities). These compounds have a B-Ni-B stretch mode originally suspected to be strongly coupled to Fermi surface (FS) electrons,^{8,9} but full calculations indicated coupling spread over much of the vibrational spectrum.¹⁰

Other Ni-based superconductors, often with C neighboring Ni, have appeared in other crystal classes. Antiperovskite $MgCNi_3^{11}$ with $T_c = 8$ K occurs with E_F lying in a narrow and extremely sharp van Hove singularity, 12 where superconductivity competes strongly with ferromagnetic tendencies in a manner that is not typical of other Ni-based superconductors. Heusler compounds such as ZrNi₂Ca which contain no C or B metalloid atom, and which are more often magnetically ordered when based on 3d transition metals, superconduct typically around $T_c \sim 3 \text{K.}^{13}$ The quaternary LaNiBN, in which Ni is coordinated with B separated by LaN layers, superconducts at 4 K (see Refs. 14,15), and its Pt analog 16 does so at 6 K. This compound is structurally and electronically ¹⁷ related to La₃Ni₂B₂N₃, also with Ni coordinated with B and superconducting at 12 K. More closely related to the compound of interest here, Th₂NiC₂, are two other compounds discovered by Fisk and collaborators: $Th_3Ni_5C_5$ with $T_c = 5$ K and the Ni-rich member of this ternary system, ThNi₄C, with¹⁹ $T_c = 5.5 \,\mathrm{K.\,A}$ "nickel carbide" LaNiC₂ superconducts at 2.7 K and electron-phonon coupling is responsible, 20 but it is based structurally on Ni-Ni and C-C dimers within a La framework rather than on Ni-C bonding.

Information so far³ points to the stoichiometric compound Th₂NiC₂ being a thermodynamically stable material only at high temperature. When alloyed on the tetravalent Th site with trivalent Sc, the material becomes stable in air and achieves the 11.2 K superconductivity mentioned above. The normal state resistivity and heat capacity follow conventional forms, and the extrapolated upper critical field is $H_{c2} \sim 11$ –12 T. MGF suggested neutral Ni d^{10} to be the appropriate picture, which we will clarify in our study of the electronic structure. The apparently vanishingly small DOS at the Fermi level is a central point of interest in this system.

In this paper we present density-functional theory (DFT) based results for the electronic properties and vibrational structure of Th_2NiC_2 at stoichiometry and when alloyed with Sc. The electronic structure is representative of what

should be treated accurately from the DFT viewpoint—the Ni electronic structure is similar to a few other Ni-C and Ni-B compounds with filled 3d bands that are described well by such calculations. Shein and Ivanovskii (SI) have provided results²¹ of electronic structure calculations but focused primarily on structural properties. We find that while Th_2NiC_2 is a relatively low $\text{N}(E_F)$, metal the extremely low (essentially vanishing) value inferred by MGF from extrapolation of heat capacity data from above T_c seems inconsistent with DFT results. Unusually fine structure in N(E) is found to lie precisely at the Fermi level, providing a resolution to some of the questions about this system and suggesting unconventional behavior, viz., thermodynamic properties.

The organization of this paper is as follows. After describing the methods and crystal structure in Sec. II, the electronic structure of Th_2NiC_2 is analyzed and contrasted with related Ni-C compounds in Sec. III. Section IV deals with the electronic structure of doped $Th_{2-x}Sc_xNiC_2$. Phonon dispersion curves of Th_2NiC_2 are presented in Sec. V, and we look at how the C-Ni-C bond stretch mode affects the electronic structure in Sec. VI, to obtain insight into possible strong coupling of this mode. In Sec. VII, the impact of band anomalies is discussed. We summarize our results in the final section.

II. CRYSTAL STRUCTURE AND THEORETICAL METHODS

The crystal structure is taken from Moss and Jeitschko⁴ and is shown in Fig. 1. The space group of Th₂NiC₂ is tetragonal I4/mmm (no. 139), with five atoms per primitive cell and lattice constants a = 3.758 Å, c = 12.356 Å. The Wyckoff positions are 4e (Th, C) and 2a (Ni), with site symmetries 4mm and 4/mmm, respectively. The internal coordinates from single-crystal x-ray data are $z_{\rm Th} = 0.354$, $z_{\rm C} = 0.156$. The nearest-neighbor distances are Ni-C 1.93 Å, Th-C 2.45 and 2.66 Å, and Th-Ni 3.21 Å. We will find it useful to consider the structure as a body centered tetragonal (bct) array of linear Th-C-Ni-C-Th units oriented along the c axis. SI have provided evidence from charge density contours of directional (presumably partially covalent) Th-C and C-Ni bonding.

The internal structure of Th₂NiC₂ was relaxed, keeping the lattice constants at their experimental values. The calculated

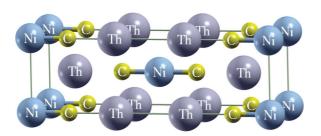


FIG. 1. (Color online) The body centered tetragonal (bct) I4/mmm U₂IrC₂ crystal structure type of Th₂NiC₂. The c axis is horizontal. The C-Ni-C trimer appears at the center of this figure; Th-C bonds discussed in the text are not shown. The structure can be pictured as a bct array of linear Th-C-Ni-C-Th units, with neighboring units containing nearly coplanar layers of Th and C atoms. The short Ni-C distance is a noteworthy aspect of the structure, but the Th-C bonds display covalent bonding aspects as well. ³⁶

relaxed values $z_{\rm Th}^c = 0.3536$, $z_C^c = 0.1545$ are very close to the observed values: that of Th is indistinguishable from the experimental value to the precision quoted for the data, and the difference of 0.0015c = 0.017 Å for the C position is small.

The linearized augmented plane wave code WiEN2K_11²² has been used unless noted otherwise. All calculations are carried out using local-density approximation (LDA). The muffin-tin radii of Th, Ni, and C are 2.44 a_0 , 1.92 a_0 , and 1.70 a_0 , respectively. The k space is sampled over a fine mesh of 3349 special k points in the irreducible wedge of the Brillouin zone. RK_{max} is chosen to be 8, making the plane wave cutoff 22.15 Ry. These values provide excellent convergence of the presented results.

Magnetic order was not obtained in the local spin density approximation, in agreement with observations and as expected from filled Ni 3d bands. As an actinide with nuclear charge Z=90, spin-orbit coupling must be included for Th, and it has been included for Ni and C as well. The Th 5f bands lie $4 \, \text{eV}$ above E_F , but significant 5f character adds to the 6d and 7p Th character due to band mixing.

III. ELECTRONIC STRUCTURE OF TH2NIC2

The band structure along bct symmetry lines, with Ni 3d orbital character emphasized by the fatband representation, is pictured in Fig. 2. In this section the experimental structure is used except where noted. The Ni 3d character lies in the -3.5 to 0.5 eV range; the Ni 3d bands are effectively filled, with some character extending to and above E_F due to hybridization. Bands crossing E_F along N-M- Γ have strong Ni d_{xz} , d_{yz} character; other bands have stronger C 2p character. The Ni d_{xy} weight lies in the -2 to -1 eV range, largely concentrated in a flat band around -1.5 eV.

The dominant feature of the band structure is an extraordinarily flat band at and near k = 0. The band can be characterized by an effective mass $m_z^* \to \infty$ (i.e., flat), with $m_x^* = m_y^*$ being large and negative. This description holds only for a small region, as seen in the lower panel of Fig. 2: along k_r to about 20% of the zone boundary and along k_z to roughly 30% of the zone boundary. This region comprises about 1% of the zone volume, i.e., 0.01 states per spin. The bottom panel of Fig. 2 demonstrates that the flat band arises due to SOC that splits the degeneracy of a band at -0.1 eV, pushing the top member of the pair precisely (and accidentally) to E_F . A band is also driven by SOC very near E_F at the zone corner. SOC expands the FS near the corner by pushing a band above E_F at R. This Fermi-level fine structure is reminiscent of the Heusler superconductor ($T_c = 2.9 \text{ K}$) ZrNi₂Ga, in which the Fermi level lies near an electronic van Hove singularity.¹³

The densities of states (DOS), total and atom-projected, are provided in Fig. 3. The total $N(E_F)=2.8$ states/eV per formula unit arises almost equally from each of the atoms. E_F lies at the center of a very narrow, 30 meV wide peak shown in the inset, that arises from the flat band discussed above. Without looking at the fine scale, the Fermi level appears to lie on the edge of a step discontinuity of the DOS. The flat band has similar size contributions from Ni (mostly d_{xz}, d_{yz}), $C(p_x, p_y)$, and Th (all of 5f, 6d, 7p). This fine structure will have an impact on the measured properties of Th_2NiC_2 , a topic we return to later.

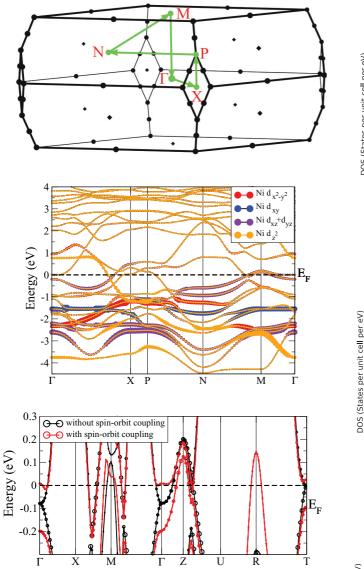


FIG. 2. (Color online) Top panel: bct Brillouin zone with paths used for the band plot in the middle panel. Middle panel: Th_2NiC_2 band structure with spin-orbit coupling included, for the experimental structure, with Ni 3d fatbands shown. Bottom panel: expanded region near the Fermi level, illustrating how spin-orbit coupling (red bands) splits a degeneracy at Γ and creates a very flat band at the Fermi level (E=0) centered at Γ . Bands without SOC are in black. A large effect of spin-orbit coupling also arises at the zone corner $R=(\pi,\pi,\pi)$. This panel uses Cartesian lines: $X=(\pi,0,0), M=(\pi,\pi,0), Z=(0,0,2\pi), U=(\pi,0,\pi), T=(0,0,\pi)$.

This fine structure is somewhat sensitive to the internal structural parameters. Also shown in the inset is N(E) when atomic positions are optimized to minimize the energy. Though the difference in atomic positions is quite small (to the accuracy provided by the experimental data the C position, and Ni-C distance, are indistinguishable), the structure is so sharp and so close to E_F that $N(E_F)$ is strongly affected. The FS of Th_2NiC_2 , shown in Fig. 4, is connected along the z axis by tubes along the zone corners. Another surface ("tube") lies in the k_x - k_y plane, which becomes the zone top (or bottom) of the next BZ. Centered at Γ is a fourfold closed surface

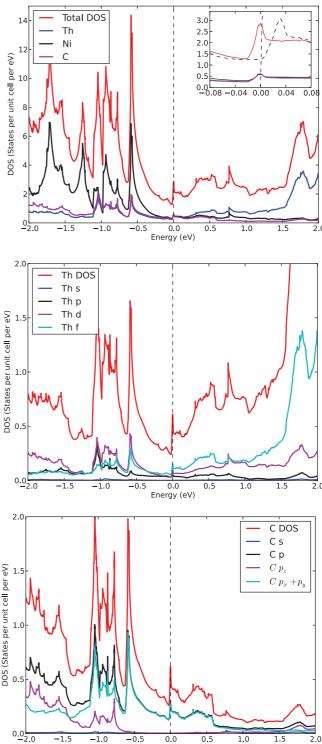


FIG. 3. (Color online) Total and orbital-projected densities of states for Th_2NiC_2 . Top panel: total and partial DOS. The DOS has very sharp structure at the Fermi level, as shown in the inset on an expanded scale. The dashed curve in the inset shows the fine structure using the relaxed atomic positions. Middle panel: Th(s,p,d,f) contributions; f and d contributions are dominant at E_F . Bottom panel: C(2s,2p) projected DOS; the negligible 2s contribution is hardly visible, and p_z is negligible at E_F .

0.0 Energy (eV)



FIG. 4. (Color online) Fermi surfaces of Th_2NiC_2 , as described in the text. The ripples of the Γ -centered sheet arise from difficult (hence inaccurate) numerical interpolation in the region of the kink in the band at the Fermi level.

of connected "cigars." Fermi surfaces near Γ are determined primarily by the flat band discussed above. Overall, the Fermi surface is representative of a good, not unusually low DOS, metal.

IV. HOLE DOPING ON THE TH SITE

Doping with Sc on the Th site increases the superconducting T_c by a few Kelvins (~30%). SI suggested that doping with Sc leads to larger density of states at the Fermi level,²¹ which could explain the increase in T_c . We have carried out two types of calculations, both including SOC and including effects beyond the rigid band behavior assumed by SI. In the first calculation, a $2 \times 2 \times 2$ supercell of the conventional cell is adopted. Four of the 32 Th atoms were substituted with Sc, giving ordered $Th_{1.75}Sc_{0.25}NiC_2$ (12.5% doping). The Sc positions were chosen as shown in Fig. 5. The small decrease in cell volume observed in experiment was neglected, and $R_{mt}K_{max}$ was reduced to 7, which is sufficient for this system. After relaxation of the atomic positions in this supercell, there are small variations of the inequivalent Ni-C bond lengths: 1.92, 1.89, and 1.90 Å. Sc-C distances are 2.29 Å (along the c direction) and 2.60Å (almost within the a-b plane.) In the pure Th₂NiC₂ compound, the Th-C bond length is 2.45 Å along the z direction and 2.66 Å (almost) within the a-b plane. The largest difference thus is in the Sc-C (versus Th-C) separation. In the second calculation the virtual crystal approximation (VCA) was adopted, with 10% hole doping being modeled by decreasing the nuclear charge of Th to 89.9, which corresponds in terms of valence electron count to Th_{1.8}Sc_{0.2}NiC₂. VCA treats the change in electron count self-consistently; hence, it is more realistic than simple rigid band, but it neglects

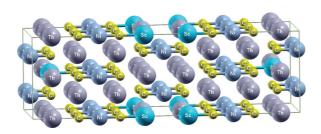


FIG. 5. (Color online) Crystal structure of the supercell calculation. Sc dopant atoms are second neighbors on the Th sublattice in the x-y plane (which is vertical in this plot).

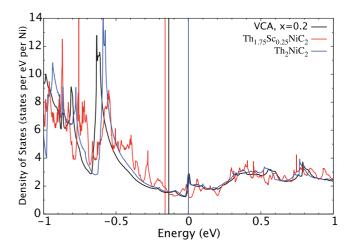


FIG. 6. (Color online) DOS for stoichiometric Th_2NiC_2 and two types of treatment of doping: virtual crystal (VCA) " $Th_{1.8}Sc_{0.2}NiC_2$ " and ordered alloy $Th_{1.75}Sc_{0.25}NiC_2 \equiv Th_7ScNi_4C_8$. The Fermi level of stoichiometric Th_2NiC_2 is chosen as the common energy zero, with the alloy results aligned at the same band filling. The Fermi level drops with doping as denoted by the horizontal lines. The ordered alloy DOS contains small sharp structure that will be broadened by random Sc substitution. See text for discussion of redistribution of spectral density due to Sc doping.

chemical and size differences. Treating doping within VCA can, however, lead to substantial changes in the electronic structure, as shown recently for the case²³ of hole doping in CuAlO₂. In that compound, substituting Mg on the Al site decreases the transfer of charge from the cation (Al, Mg) to Cu, with a resulting dipole-layer shift in potential. In that compound the electronic structure changes dramatically, with a strong decrease in the strength of electron-phonon coupling.

Because N(E) in Th_2NiC_2 near E_F arises equally from the three atoms, the change in valence electron density due to doping will be spread evenly throughout the cell, and indeed we find relatively minor differences compared to the rigid band picture. Comparison of N(E) for the three calculations is provided in Fig. 6. To better assess the effect of doping on the spectrum, the density of states of both alloy models was shifted for display so that the total numbers of states per unit cell below E=0 are the same. The virtual crystal calculation results in rigid band behavior down to and somewhat beyond the Fermi level of the doped material. Due to the DOS fine structure, doping by the first ~ 0.01 holes may decrease N(E_F) by up to a factor of 2; as pointed out in Sec. III, the fine structure and thus $N(E_F)$ is sensitive to the internal parameters. Beyond the initial drop, N(E) recovers slowly and nonmonotonically with further hole doping.

For the supercell with 12.5% ordered Sc substitutionals, the profusion of bands $(2 \times 2 \times 2)$ times as many) with their anticrossings gives rise to numerous additional van Hove singularities in N(E) because the supercell has 16 times as many bands as the original compound. This complexity is configuration specific, and the DOS will be smeared in the disordered alloy. Without knowledge of the amount of smearing, which would require a coherent potential approximation alloy calculation to reveal, spectral shifts cannot be determined with certainty. However, the decrease in the strength of the

peak near -0.6 eV and increase in the DOS in the -0.5 to -0.15 eV range in the supercell calculation suggests that Sc doping does lead to some general increase in spectral density in this region beyond what the VCA picture gives.

The very fine structure precisely at E_F for the stoichiometric compound suggests a scenario that may account for the increased T_c with hole doping. Ternary compounds can be difficult to prepare in absolutely stoichiometric form, and the difficulty is increased for marginally stable materials. We suspect therefore that Th₂NiC₂ as synthesized is slightly hole doped; this will decrease N(E_F) by up to a factor of 2 and increase its stability due to the reduction of the charge and spin susceptibilities. With respect to this "undoped" reference material, Sc doping by 5–10% should indeed increase N(E_F) somewhat and therefore increase T_c , more or less as observed.

V. PHONON DISPERSION

Based on experience from several other intermetallic Ni-based superconductors, we pursue the likelihood that the superconducting mechanism is electron-phonon coupling, so assessment of the phonon dispersion curves is needed. The code PHONOPY²⁴ was used. For this, forces calculated from finite displacements of atoms in a $3 \times 3 \times 1$ supercell are used to compute the elastic constants which can be used to calculate the dynamic matrix at an arbitrary q point. The relaxed atomic positions were used as the reference structure; as noted in Sec. II these positions are close to the experimental values. Kohn anomalies, which are not evident here, would be reproduced in a smoothed fashion with this method, since they involve very long-range force constants.

The resulting dispersion along bct symmetry lines is displayed in Fig. 7 and mostly shows weak dispersion throughout the zone. It is worthwhile to distinguish the four (of the fifteen) branches with polarization along \hat{z} and consider them in terms of the linear Th-C-Ni-C-Ni unit. There are two symmetric, Raman-active A_{1g} modes in which Ni is static; the symmetric C and Th motions can be either in phase or out of phase. The

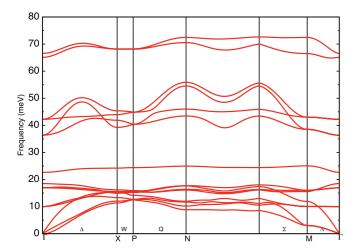


FIG. 7. (Color online) Dispersion of phonon branches along the symmetry line path shown in Fig. 2(a), for stoichiometric Th_2NiC_2 . All branches are relatively dispersionless except for the necessarily linear acoustic modes. The phonon frequency is expressed in units of meV (1 THz = 4.14 meV)

odd, IR-active A_{1u} modes involve displaced Ni (along, say, $+\hat{z}$), with one of the C and Th displacements in phase and one out of phase (the center of mass must be stationary).

The phonon branches separate into four distinct energy regions.

- (1) The eight branches below 18 meV include the three acoustic branches, which contain contributions from all atoms. This complex also contains two pairs of degenerate optic modes, one composed primarily of Th and C motions along $\pm \hat{x}$ and (degenerately) along $\pm \hat{y}$ and the other pair involving all three atoms moving in the x-y plane with Th moving out of phase with Ni and C. The final mode in this complex, which lies in this same frequency range only accidentally, is a C-Th stretch mode polarized along the \hat{z} axis with a stationary Ni atom, whose dispersionless nature suggests a picture of a local mode for this vibration.
- (2) There is a single nondispersive branch at 25 meV which involves motion of all atoms along the c axis: Th along $+\hat{z}$ and both N and C along $-\hat{z}$. Thus, this is the C-Ni-C trimer moving out of phase with the Th atoms in the Th-C-Ni-C-Th unit.
- (3) Four branches in the 35–55-meV range contain one degenerate pair with in-plane C displacements in the \hat{x} (and \hat{y}) direction, and another pair with similar frequency that involve C along $+\hat{x}$ and Ni along $-\hat{x}$, and its degenerate partner. Thorium is involved in only a very minor way in these modes, as anticipated by their high energy.
- (4) The two highest frequency branches around 70 meV involve Ni-C stretch motion of a relatively strong bond and vibration of the light C atoms. One has the two C atoms moving out of phase with the Ni atom, while for the other the Ni atom is stationary.

As mentioned earlier, evidence of directional (viz., covalent) Th-C bonding as well as Ni-C bonding along the c axis was provided by SI in density contour plots, whereas bonding within the a-b plane is essentially metallic throughout the structure. This covalent bonding is reflected in the character of the high-frequency modes.

VI. FROZEN ATOM DISPLACEMENTS

To study the sensitivity of individual bands at the Fermi surface to the Ni-C bond stretch, C atoms were displaced to $z_C = 0.170$, a rather large 0.17-Å displacement that allows easier identification of the deformation potentials (the rate of change of band energy with respect to atomic motion, which reflects an important contribution to electron-phonon matrix elements). The resulting band structure near E_F is plotted along with that of the equilibrium structure in Fig. 8. From the Ni fat band character included in Fig. 8, one can observe that bands with strong Ni character are influenced much less by this C displacement compared with bands with little Ni character, which have more C and Th character. The deformation potentials range from nearly zero up to 2 eV/Å, indicating significant but not unusually large coupling to Fermi-surface states. Note that the largest coupling is to the zone center flat band at E_F .

For some indication of the coupling of Th motion to electronic states, Th was displaced along the c axis by 0.1 Å, again a large phonon amplitude for a heavy atom. Even so,

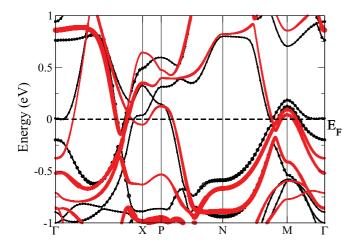


FIG. 8. (Color online) Bands near E_F before and after C displacement along the stretch mode. Note that the shift of the flat band at Γ , more than 2 eV/Å, is one of the largest. Black: Ni 3d character in Th₂NiC₂ with undisplaced C atom, with a Ni-C distance of 1.9275 Å. Red: Nickel 3d character in Th₂NiC₂ with C atom displaced to a Ni-C bond length of 2.1005 Å. Band shifts near E_F relevant to electron-phonon coupling are discussed in the text.

the bands near the Fermi level shift very little compared to C displacement, indicating weak coupling to Th motion.

VII. IMPACT OF BAND ANOMALIES

Unusual behavior of a material can often be linked directly to fine structure at E_F , with examples showing new characteristics appearing recently. The most common situation is that of conventional van Hove singularities (see below), which are generic to a band structure. More interesting because they are unconventional are other types of band anomalies. An example showing some similarities to Th₂NiC₂ is NaAlSi: it is a ternary semimetal with superconducting $T_c = 7$ K and displays an unusually sharp peak in N(E) at the Fermi level due to hybridization between slightly overlapping valence and conduction bands.²⁵ Another example is the intermetallic compound NbFe2, which displays a quantum critical point slightly off stoichiometry.²⁶ Study of the band structure led to the prediction that the critical behavior is due to a van Hove singularity with one divergent effective mass²⁷ (a $[\delta k]^3$ dispersion in one direction) that was confirmed by coherent potential approximation alloy calculations.²⁸ The enigmatic intermetallic compound TiBe2, a highly enhanced incipient ferromagnet with strongly temperature dependent susceptibility and Knight shift, displays DOS fine structure²⁹ at E_F as well.

Experimentally, the interesting features of Th_2NiC_2 are (1) superconductivity in a new Ni-based material, (2) T_c enhanced by 30% by minor doping by Sc, and (3) the extrapolation of the heat capacity, suggesting vanishing electronic DOS at the Fermi level and causing questions about the observed metallic and superconducting behavior. These first-principles calculations presented above reveal unusually fine structure in the electronic bands at E_F , structure that should affect several properties of the undoped compound. In this case, the fine structure is due to spin-orbit coupling induced

splitting of band degeneracies together with the usual mixing of bands. The effective Fermi energy $\varepsilon_F \sim 10$ meV implies nondegenerate electron gas behavior beginning at a few tens of Kelvins; the energy variation of N(E) requires attention when considering thermodynamic and transport coefficients. The standard simple use of " $N(E_F)$ " has to be replaced with a formalism that incorporates the nondegeneracy. Additionally, the Ni-C stretch mode with energy $\omega_s = 70$ meV, which seems moderately strongly coupled to FS states and is a candidate for the pairing mechanism, will have nonadiabatic contributions: N(E) varies strongly over the regions $(-\omega_s, \omega_s)$ so that standard Eliashberg theory based on the Born-Oppenheimer approximation no longer holds. It should also be noted that N(E) beyond the narrow peak on the positive energy side is \sim 50% larger than on the negative energy side; electron and hole doping should be substantially different, with electron doping providing larger $N(E_F)$.

Variation of N(E) on a scale of importance for properties, discussed especially for van Hove singularities, has a long history and large literature. This area of interest was spurred initially by the flat bands and van Hove singularities that arise in the superconducting A15 compounds^{30–33} and figured even more prominently for the high-temperature superconducting cuprates; see, for example, Ref. 34. A general formalism for including effects of both thermal smearing and electronphonon broadening was given by one of the present authors.³⁵ At the most fundamental level, the chemical potential ("Fermi level") becomes dependent on temperature. For the symmetric peak in N(E) that we obtain, this shift may be minor; however, off stoichiometry can readily change this. In the normal state, DOS variation affects the spin susceptibility and transport properties as well as the electronic heat capacity and also complicates the effects due to defects³⁵ through broadening of N(E).

VIII. SUMMARY

First-principles methods have been applied to illuminate the electronic, vibrational, and doping behavior in the newly discovered superconductor Th_2NiC_2 . While the Fermi level is found to fall in a rather low density of states region, we obtain a value of $N(E_F)$ that should be easily detectable experimentally and which we have not been able to reconcile with the extrapolation of specific-heat data from above T_c that implies an essentially vanishing $N(E_F)$. The Ni 3d bands of this compound are essentially filled, consistent with a "neutral Ni" picture, but some regions of the Fermi surface still have considerable Ni character while other portions are more heavily C derived.

The distinctive aspect of the electronic structure is very fine structure lying precisely (but accidentally) at the Fermi level, a result that is only obtained when spin-orbit coupling is included. Slight hole doping (\sim 1%) can change N(E_F) by a factor of 2, and it is plausible that such intrinsic hole doping helps to stabilize the material. From this reference point, the rise in N(E_F) with further doping can help to account for the observed increase in T_c with hole doping. Within this scenario, electron doping would strongly increase N(E_F) and thereby the superconducting T_c .

Doping with Sc for Th that increases T_c by 30% in this system has been studied in two ways: virtual crystal approximation and substitutional replacement in a supercell. While VCA gives a rigid band result as anticipated, the supercell method suggests there is some shift in spectral density just below the Fermi level due to Th replacement by Sc. The movement of the Fermi level downward by this substitution also results in somewhat stronger Ni-C bonding character and hence larger electron-phonon matrix elements participating in an increase in T_c . The phonon dispersion curves display distinct clusters of branches distributed up to 70 meV. The two high-frequency branches derive from the C-Ni-C stretch modes.

Frozen phonon calculations involving displacements of (separately) the C and Th atoms indicate significant electronphonon coupling of the C atoms but insignificant coupling to Th motion. The superconductivity in this system seems consistent with an electron-phonon mechanism, as seems to be the case in most other Ni-C superconductors such as those mentioned in the Introduction, but we do not have a quantitative estimate of the strength of coupling. The phonon calculations do not include Th substitution by Sc, but an interesting possibility is that the light Sc atom could produce a local-mode vibron and possible unconventional contribution to electron-phonon coupling.

ACKNOWLEDGMENTS

We thank Z. Fisk for early notification of the experimental data on Th₂NiC₂. This work was supported by US Department of Energy SciDAC Grant No. DE-FC02-06ER25794 and a collaborative effort with the Energy Frontier Research Center *Center for Emergent Superconductivity* through SciDAC-e Grant No. DE-FC02-06ER25777.

¹J. Nagamatsu, N. Nakagawa, T. Muranka, Y. Zenitani, and J. Akimitsu, Nature (London) **410**, 63 (2001).

 ²S. L. Bud'ko, G. Lapertot, C. Petrovic, C. E. Cunningham, N. Anderson, and P. C. Canfield, Phys. Rev. Lett. **86**, 1877 (2001).
³A. J. S. Machado, T. Grant, and Z. Fisk, Supercond. Sci. Technol. **25**, 045010 (2012).

⁴M. A. Moss and W. Jeitschko, Z. Anorg. Allg. Chem. **603**, 57 (1991).

⁵R. Nagarajan, C. Mazumdar, Z. Hossain, S. K. Dhar, K. V. Gopalakrishnan, L. C. Gupta, C. Godart, B. D. Padalia, and R. Vijayaraghavan, Phys. Rev. Lett. **72**, 274 (1994).

⁶R. J. Cava *et al.*, Nature (London) **367**, 252 (1994).

⁷L. F. Mattheiss, T. Siegrist, and R. J. Cava, Solid State Commun. **91**, 587 (1994).

⁸W. E. Pickett and D. J. Singh, Phys. Rev. Lett. **72**, 3702 (1994).

⁹W. E. Pickett and D. J. Singh, J. Supercond. **8**, 425 (1995).

¹⁰W. Reichardt, R. Heid, and K. P. Bohnen, J. Supercond. **18**, 759 (2005).

¹¹T. He *et al.*, Nature (London) **411**, 54 (2001).

¹²H. Rosner, R. Weht, M. D. Johannes, W. E. Pickett, and E. Tosatti, Phys. Rev. Lett. **88**, 027001 (2001).

¹³J. Winterlik, G. H. Fecher, C. Felser, M. Jourdan, K. Grube, F. Hardy, H. von Löhneysen, K. L. Holman, and R. J. Cava, Phys. Rev. B **78**, 184506 (2008).

¹⁴H. W. Zandbergen, J. Jansen, R. J. Cava, J. J. Krajewski, and W. F. Peck, Jr., Nature (London) **372**, 759 (1994).

¹⁵M.-J. Jung and K.-W. Lee (unpublished).

¹⁶N. Imamura, H. Mizoguchi, and H. Hosono, J. Am. Chem. Soc. 134, 2516 (2012).

¹⁷D. J. Singh and W. E. Pickett, Phys. Rev. B **51**, 8668 (1995).

¹⁸A. J. S. Machado, T. Grant, and Z. Fisk, Supercond. Sci. Technol. 24, 095007 (2011).

¹⁹T. Grant, A. J. S. Machado, C. Capan, and Z. Fisk, Bull. Amer. Phys. Soc. X **41**, 00001 (2010), http://meetings.aps.org/link/BAPS.2010.MAR.X41.1.

²⁰A. Subedi and D. J. Singh, Phys. Rev. B **80**, 092506 (2009).

²¹I. R. Shein and A. L. Ivanovskii, arXiv:1208.4456.

²²K. Schwarz and P. Blaha, Comp. Mat. Sci. **28**, 259 (2003).

²³E. R. Ylvisaker and W. E. Pickett, Europhys. Lett. **101**, 57006 (2013).

²⁴A. Togo, F. Oba, and I. Tanaka, Phys. Rev. B **78**, 134106 (2008).

²⁵H. B. Rhee, S. Banerjee, E. R. Ylvisaker, and W. E. Pickett, Phys. Rev. B **81**, 245114 (2010).

²⁶M. Brando, W. J. Duncan, D. Moroni-Klementowicz, C. Albrecht, D. Gruner, R. Ballou, and F. M. Grosche, Phys. Rev. Lett. 101, 026401 (2008).

²⁷B. P. Neal, E. R. Ylvisaker, and W. E. Pickett, Phys. Rev. B 84, 085133 (2011).

²⁸A. Alam and D. D. Johnson, Phys. Rev. Lett. **107**, 206401 (2011).

²⁹T. Jeong, A. Kyker, and W. E. Pickett, Phys. Rev. B **73**, 115106 (2006).

³⁰W. E. Pickett, Phys. Rev. Lett. **48**, 1548 (1982).

³¹W. E. Pickett, Phys. Rev. B **21**, 3897 (1980).

³²E. Schachinger and J. P. Carbotte, J. Phys. F **13**, 2615 (1983).

³³J. K. Freericks, A. Y. Liu, A. Quandt, and J. Geerk, Phys. Rev. B 65, 224510 (2002).

³⁴R. J. Radtke and M. R. Norman, Phys. Rev. B **50**, 9554 (1994).

³⁵W. E. Pickett, Phys. Rev. B **26**, 1186 (1982).

³⁶A. Kokalj, Comp. Mater. Sci. 28, 155 (2003), code available from http://www.xcrysden.org/.